TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74LCX00F,TC74LCX00FN,TC74LCX00FT,TC74LCX00FK

Low-Voltage Quad 2-Input NAND Gate with 5-V Tolerant Inputs and Outputs

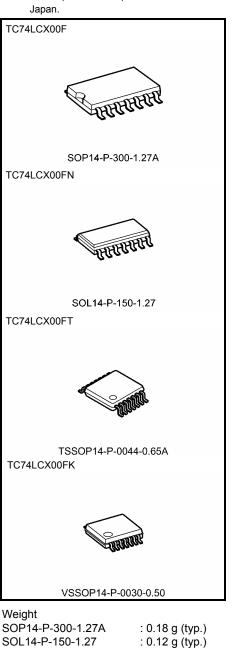
The TC74LCX00 is a high-performance CMOS 2-input NAND gate. Designed for use in 3.3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

The device is designed for low-voltage (3.3 V) V_{CC} applications, but it could be used to interface to 5 V supply environment for inputs.

All inputs are equipped with protection circuits against static discharge.

Features

- Low-voltage operation: $V_{CC} = 2.0$ to 3.6 V .
- High-speed operation: $t_{pd} = 5.2 \text{ ns} (max) (V_{CC} = 3.0 \text{ to } 3.6 \text{ V})$ ٠
- Output current: $|I_{OH}|/I_{OL} = 24 \text{ mA} (\text{min}) (V_{CC} = 3.0 \text{ V})$ •
- Latch-up performance: -500 mA
- Available in JEDEC SOP, JEITA SOP, TSSOP and . VSSOP (US)
- Power-down protection provided on all inputs and outputs ٠
- Pin and function compatible with the 74 series (74AC/VHC/HC/F/ALS/LS etc.) 00 type



TSSOP14-P-0044-0.65A

VSSOP14-P-0030-0.50

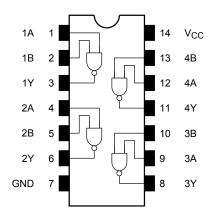
Downloaded from Elcodis.com electronic components distributor

: 0.06 g (typ.)

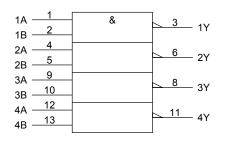
: 0.02 g (typ.)

Note: xxxFN (JEDEC SOP) is not available in

Pin Assignment (top view)



IEC Logic Symbol



Truth Table

| Inp | uts | Outputs |
|-----|-----|---------|
| А | В | Y |
| L | L | н |
| L | Н | н |
| Н | L | н |
| Н | Н | L |

Absolute Maximum Ratings (Note 1)

| Characteristics | Symbol | Rating | Unit | |
|------------------------------------|-----------------------------------|---|------|--|
| Power supply voltage | V _{CC} | -0.5 to 7.0 | V | |
| DC input voltage | V _{IN} | -0.5 to 7.0 | V | |
| | | -0.5 to 7.0 (Note 2) | | |
| DC output voltage | Vout | -0.5 to V _{CC} + 0.5 (Note 3) | V | |
| Input diode current | Iк | -50 | mA | |
| Output diode current | I _{ОК} | ±50 (Note 4) | mA | |
| DC output current | IOUT | ±50 | mA | |
| Power dissipation | PD | 180 | mW | |
| DC V _{CC} /ground current | I _{CC} /I _{GND} | ±100 | mA | |
| Storage temperature | T _{stg} | –65 to 150 | °C | |

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: $V_{CC} = 0 V$

Note 3: High or low state. I_{OUT} absolute maximum rating must be observed.

Note 4: $V_{OUT} < GND, V_{OUT} > V_{CC}$

Operating Ranges (Note 1)

| Characteristics | Symbol | Rating | Unit |
|--------------------------|------------------|------------------------|------|
| Power supply voltage | Vcc | 2.0 to 3.6 | V |
| Tower supply voltage | vcc | 1.5 to 3.6 (Note 2) | v |
| Input voltage | V _{IN} | 0 to 5.5 | V |
| Output voltage | Vout | 0 to 5.5 (Note 3) | V |
| Output voltage | | 0 to V_{CC} (Note 4) | v |
| Output current | Іон/Іог | ±24 (Note 5) | mA |
| Output current | IOH/IOL | ±12 (Note 6) | IIIA |
| Operating temperature | T _{opr} | -40 to 85 | °C |
| Input rise and fall time | dt/dv | 0 to 10 (Note 7) | ns/V |

Note 1: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

Note 2: Data retention only

Note 3: $V_{CC} = 0 V$

Note 4: High or low state

Note 5: $V_{CC}=3.0 \mbox{ to } 3.6 \mbox{ V}$

Note 6: $V_{CC} = 2.7$ to 3.0 V

Note 7: $V_{IN}=0.8$ to 2.0 V, $V_{CC}=3.0$ V

Electrical Characteristics

DC Characteristics (Ta = -40 to 85°C)

| Characteri | istics | Symbol | Test Condition | | V _{CC} (V) | Min | Max | Unit |
|--------------------------|---------|-----------------------------------|-----------------------------------|---------------------------|--------------------------|-------|------|-----------------------|
| | H-level | VIH | | | | 2.0 | _ | |
| Input voltage | L-level | VIL | | | 2.7 to 3.6 | _ | 0.8 | V |
| | | | I _{OH} = -100 μA | 2.7 to 3.6 | V _{CC} - 0.2 | | | |
| | H-level | VOH | VIN = VIH or VIL | $I_{OH} = -12 \text{ mA}$ | 2.7 | 2.2 | _ | - - - - - |
| | | | | $I_{OH} = -18 \text{ mA}$ | 3.0 | 2.4 | | |
| Output voltage | | | | $I_{OH} = -24 \text{ mA}$ | 3.0 | 2.2 | _ | |
| | | el V _{OL} | VIN = VIH | $I_{OL} = 100 \ \mu A$ | 2.7 to 3.6 | _ | 0.2 | |
| | L-level | | | $I_{OL} = 12 \text{ mA}$ | 2.7 | | 0.4 | |
| L-level | L-IEVEI | | | $I_{OL} = 16 \text{ mA}$ | 3.0 | | 0.4 | |
| | | | $I_{OL} = 24 \text{ mA}$ | 3.0 | _ | 0.55 | | |
| Input leakage curre | nt | I _{IN} | $V_{IN} = 0$ to 5.5 V | | 2.7 to 3.6 | | ±5.0 | μA |
| Power off leakage | current | I _{OFF} | $V_{IN}/V_{OUT} = 5.5 V$ | | 0 | | 10.0 | μA |
| Quiescent supply current | Icc | $V_{IN} = V_{CC} \text{ or } GND$ | | 2.7 to 3.6 | | 10.0 | | |
| | | V _{IN} = 3.6 to 5.5 V | | 2.7 to 3.6 | | ±10.0 | 0 μΑ | |
| Increase in Icc per | input | ∆ICC | $V_{IH} = V_{CC} - 0.6 \text{ V}$ | | 2.7 to 3.6 | _ | 500 | |

AC Characteristics (Ta = -40 to 85°C)

| Characteristics | Symbol | Test Condition | V _{CC} (V) | Min | Max | Unit |
|------------------------|-------------------|--------------------|-------------------------------|-----|-----|------|
| Propagation delay time | t _{pLH} | Figure 1, Figure 2 | 2.7 | _ | 6.0 | ns |
| | t _{pHL} | | $\textbf{3.3}\pm\textbf{0.3}$ | 1.5 | 5.2 | |
| Output to output skew | t _{osLH} | (histo) | 2.7 | _ | | 20 |
| | t _{osHL} | (Note) | $\textbf{3.3}\pm\textbf{0.3}$ | | 1.0 | ns |

Note: Parameter guaranteed by design.

 $(t_{osLH} = |t_{pLHm} - t_{pLHn}|, t_{osHL} = |t_{pHLm} - t_{pHLn}|)$

Dynamic Switching Characteristics (Ta = 25°C, input: $t_r = t_f = 2.5$ ns, $C_L = 50$ pF, $R_L = 500 \Omega$)

| Characteristics | Symbol | Test Condition | V _{CC} (V) | Тур. | Unit |
|---------------------------------------|------------------|--------------------------------|---------------------|------|------|
| Quiet output maximum dynamic V_{OL} | VOLP | $V_{IH} = 3.3 V, V_{IL} = 0 V$ | 3.3 | 0.8 | V |
| Quiet output minimum dynamic V_{OL} | V _{OLV} | $V_{IH} = 3.3 V, V_{IL} = 0 V$ | 3.3 | 0.8 | V |

Capacitive Characteristics (Ta = 25°C)

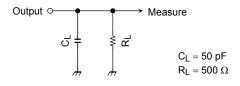
| Characteristics | Symbol | Test Condition | V _{CC} (V) | Тур. | Unit |
|-------------------------------|------------------|---------------------------------|---------------------|------|------|
| Input capacitance | C _{IN} | — | 3.3 | 7 | pF |
| Output capacitance | C _{OUT} | | 0 | 8 | pF |
| Power dissipation capacitance | CPD | f _{IN} = 10 MHz (Note) | 3.3 | 25 | pF |

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

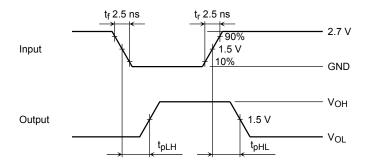
 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/4 (per gate)$

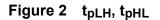
AC Test Circuit





AC Waveform

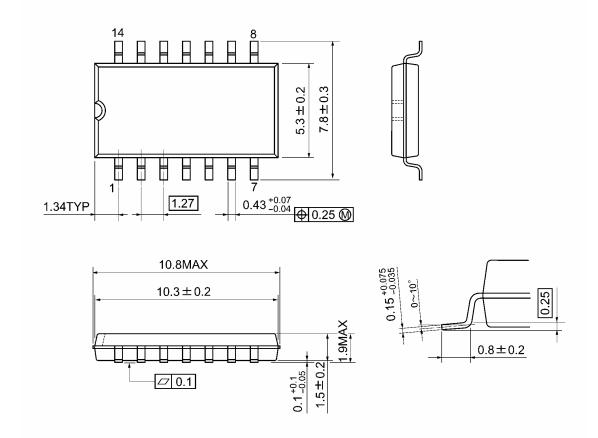




Package Dimensions

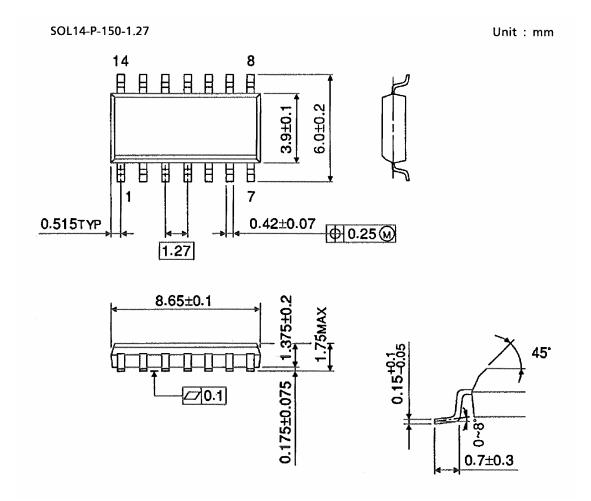
SOP14-P-300-1.27A

Unit: mm



Weight: 0.18 g (typ.)

Package Dimensions (Note)



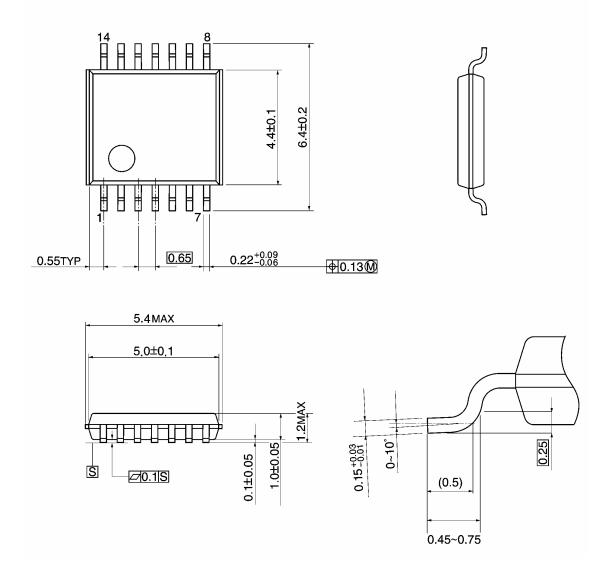
Note: This package is not available in japan.

Weight: 0.12 g (typ.)

Package Dimensions

TSSOP14-P-0044-0.65A

Unit: mm

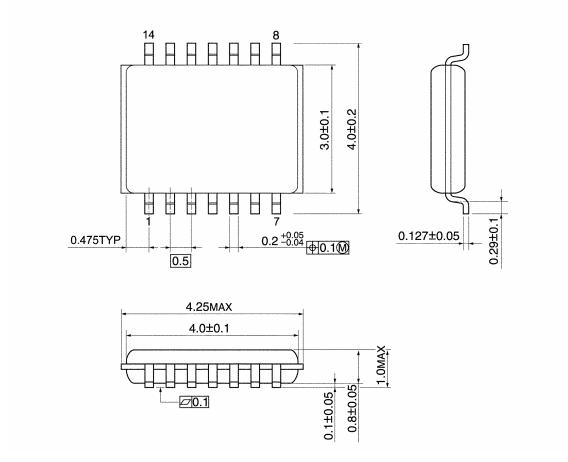


Weight: 0.06 g (typ.)

Package Dimensions

VSSOP14-P-0030-0.50

Unit: mm



Weight: 0.02 g (typ.)

9

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20070701-EN GENERAL

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